

### FEATURES

- Double Side Cooling
- High Surge Capability

### APPLICATIONS

- High Power Drives
- High Voltage Power Supplies
- Static Switches

### VOLTAGE RATINGS

Part and Ordering Number	Repetitive Peak Voltages $V_{DRM}$ and $V_{RRM}$ V	Conditions
DCR2980C14	1400	$T_{vj} = -40^{\circ}\text{C}$ to $125^{\circ}\text{C}$ , $I_{DRM} = I_{RRM} = 250\text{mA}$ , $V_{DRM}, V_{RRM} t_p = 10\text{ms}$ , $V_{DSM} \ \& \ V_{RSM} =$ $V_{DRM} \ \& \ V_{RRM} + 100\text{V}$ respectively
DCR2980C12	1200	
DCR2980C10	1000	
DCR2980C08	800	
DCR2980C06	600	

Lower voltage grades available.

### ORDERING INFORMATION

When ordering, select the required part number shown in the Voltage Ratings selection table.

For example:

#### DCR2980C14

Note: Please use the complete part number when ordering and quote this number in any future correspondence relating to your order.

### KEY PARAMETERS

$V_{DRM}$	1400 V
$I_{T(AV)}$	2980 A
$I_{TSM}$	47000 A
$dV/dt^*$	1000 V/ $\mu\text{s}$
$dI/dt$	200 A/ $\mu\text{s}$

\* Higher  $dV/dt$  selections available

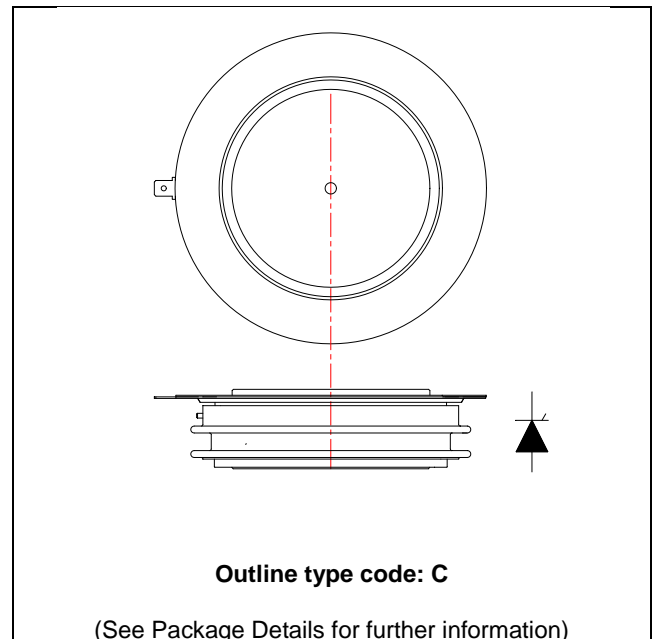


Fig. 1 Package outline

### CURRENT RATINGS

T<sub>case</sub> = 60°C unless stated otherwise

Symbol	Parameter	Test Conditions	Max.	Units
<b>Double Side Cooled</b>				
I <sub>T(AV)</sub>	Mean on-state current	Half wave resistive load	2980	A
I <sub>T(RMS)</sub>	RMS value	-	4680	A
I <sub>T</sub>	Continuous (direct) on-state current	-	4210	A

### SURGE RATINGS

Symbol	Parameter	Test Conditions	Max.	Units
I <sub>TSM</sub>	Surge (non-repetitive) on-state current	10ms half sine, T <sub>case</sub> = 125°C	47.0	kA
I <sup>2</sup> t	I <sup>2</sup> t for fusing	V <sub>R</sub> = 0	11.05	MA <sup>2</sup> s

### THERMAL AND MECHANICAL RATINGS

Symbol	Parameter	Test Conditions	Min.	Max.	Units
R <sub>th(j-c)</sub>	Thermal resistance – junction to case	Double side cooled	-	0.0125	°C/W
R <sub>th(c-h)</sub>	Thermal resistance – case to heatsink	Double side cooled	-	0.004	°C/W
T <sub>vj</sub>	Virtual junction temperature	Blocking V <sub>DRM</sub> / V <sub>RRM</sub>	-	125	°C
T <sub>stg</sub>	Storage temperature range		-40	140	°C
F <sub>m</sub>	Clamping force		40	50	kN

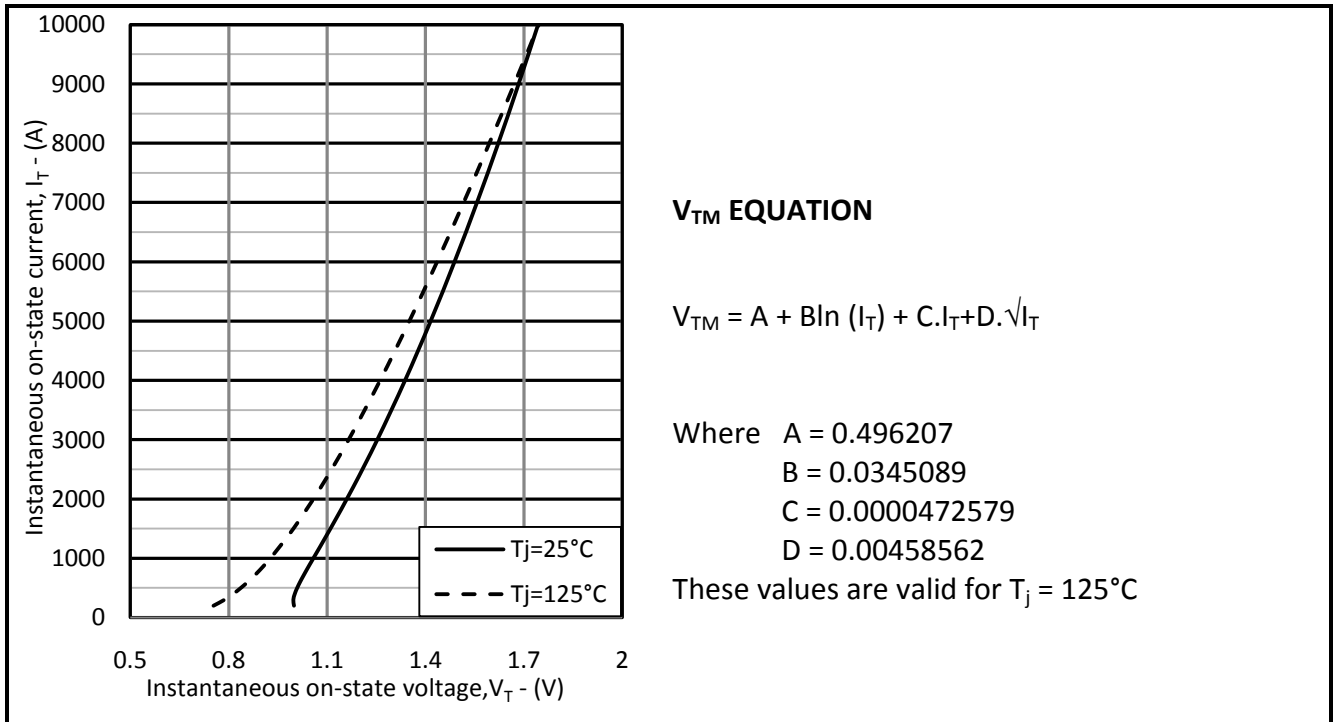
**DYNAMIC CHARACTERISTICS**

Symbol	Parameter	Test Conditions	Min.	Max.	Units	
$I_{RRM}/I_{DRM}$	Peak reverse and off-state current	At $V_{RRM}/V_{DRM}$ , $T_{case} = 125^{\circ}C$	-	250	mA	
$dV/dt$	Max. linear rate of rise of off-state voltage	To 67% $V_{DRM}$ , $T_j = 125^{\circ}C$ , gate open	1000	-	V/ $\mu$ s	
$di/dt$	Rate of rise of on-state current	From 67% $V_{DRM}$ to 4000A Gate source 30V, 10 $\Omega$ , $t_r < 0.5\mu$ s, $T_j = 125^{\circ}C$	Repetitive 50Hz	-	200	A/ $\mu$ s
			Non-repetitive	-	1000	A/ $\mu$ s
$V_T$	On-state voltage	$I_T = 3000A$ , $T_{case} = 125^{\circ}C$		1.16	V	
$V_{T(TO)}$	Threshold voltage	$T_{case} = 125^{\circ}C$	-	0.87	V	
$r_T$	On-state slope resistance	$T_{case} = 125^{\circ}C$	-	0.098	m $\Omega$	
$t_{gd}$	Delay time	$V_D = 67\% V_{DRM}$ , gate source 30V, 10 $\Omega$ $t_r = 0.5\mu$ s, $T_j = 25^{\circ}C$	-	3.0	$\mu$ s	
$t_q$	Turn-off time	$T_j = 125^{\circ}C$ , $V_R = 100V$ , $di/dt = 10A/\mu$ s, $dV_{DR}/dt = 20V/\mu$ s linear to 67% $V_{DRM}$	-	300	$\mu$ s	
$Q_S$	Stored charge	$I_T = 4000A$ , $t_p = 1000\mu$ s, $T_j = 125^{\circ}C$ , $di/dt = 10A/\mu$ s,	-	2600	$\mu$ C	
$I_{RR}$	Reverse recovery current		-	155	A	
$I_L$	Latching current	$T_j = 25^{\circ}C$ ,	-	1	A	
$I_H$	Holding current	$T_j = 25^{\circ}C$ ,	-	200	mA	

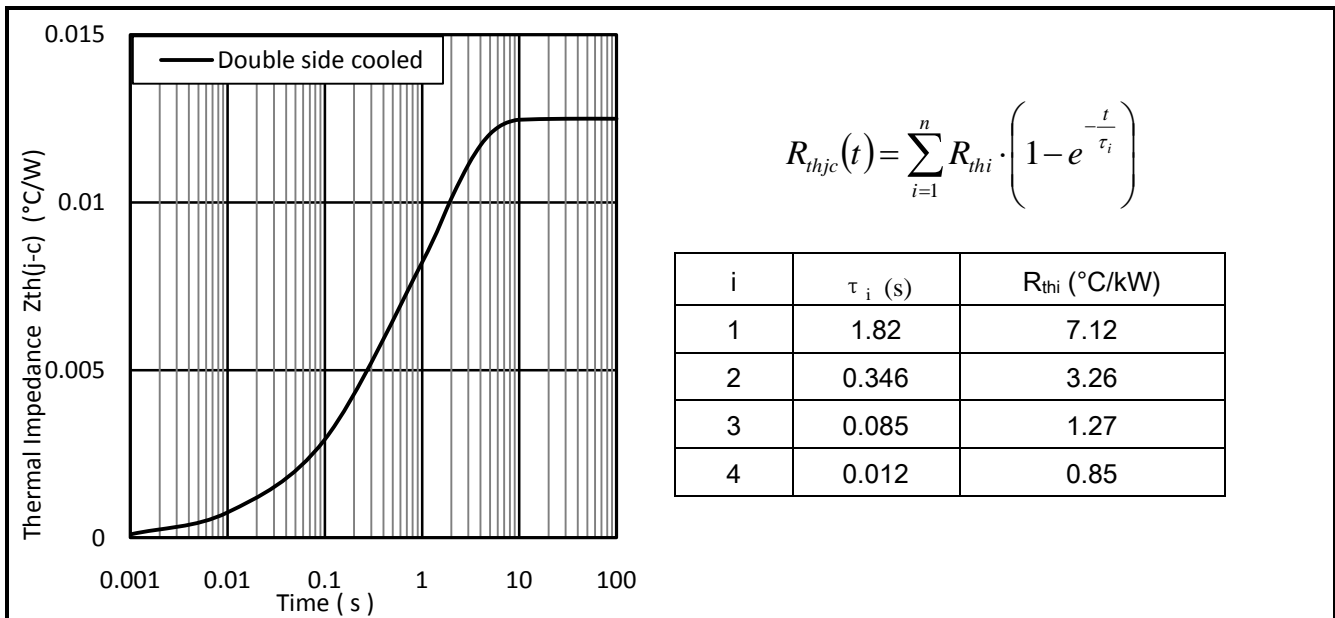
**GATE TRIGGER CHARACTERISTICS AND RATINGS**

Symbol	Parameter	Test Conditions	Max.	Units
$V_{GT}$	Gate trigger voltage	$V_{DRM} = 5V$ , $T_{case} = 25^{\circ}C$	3	V
$V_{GD}$	Gate non-trigger voltage	At 40% $V_{DRM}$ , $T_{case} = 125^{\circ}C$	TBD	V
$I_{GT}$	Gate trigger current	$V_{DRM} = 5V$ , $T_{case} = 25^{\circ}C$	300	mA
$I_{GD}$	Gate non-trigger current	At 40% $V_{DRM}$ , $T_{case} = 125^{\circ}C$	TBD	mA

**CURVES**



**Fig.2 Maximum & minimum on-state characteristics**



**Fig.3 Maximum (limit) transient thermal impedance – junction to case (°C/W)**

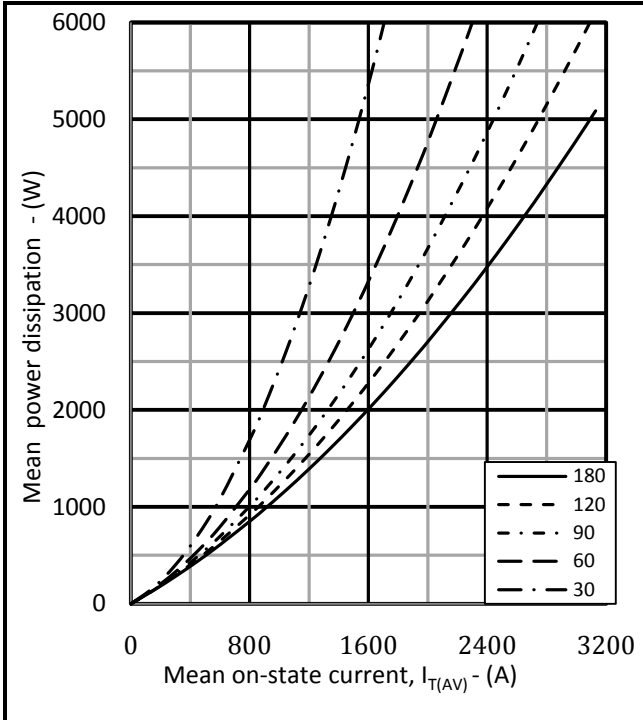


Fig.4 On-state power dissipation – sine wave

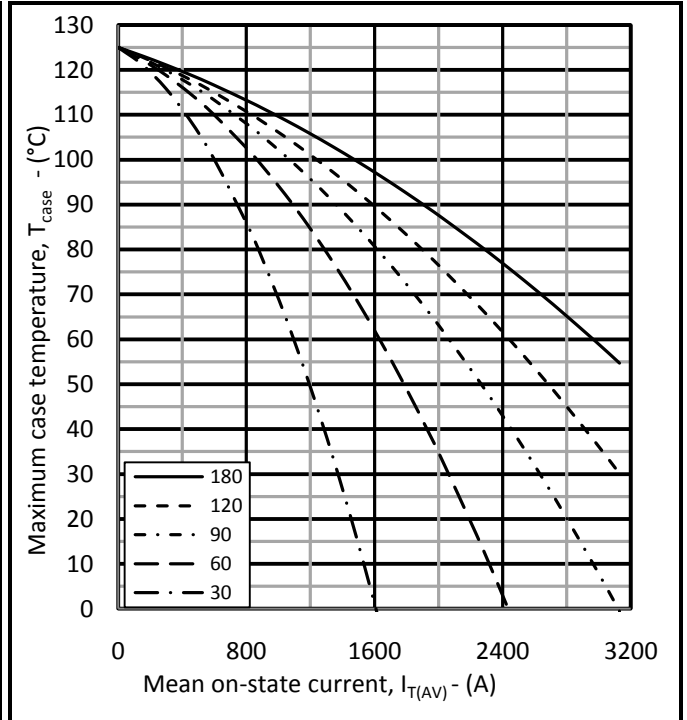


Fig.5 Maximum permissible case temperature, double side cooled – sine wave

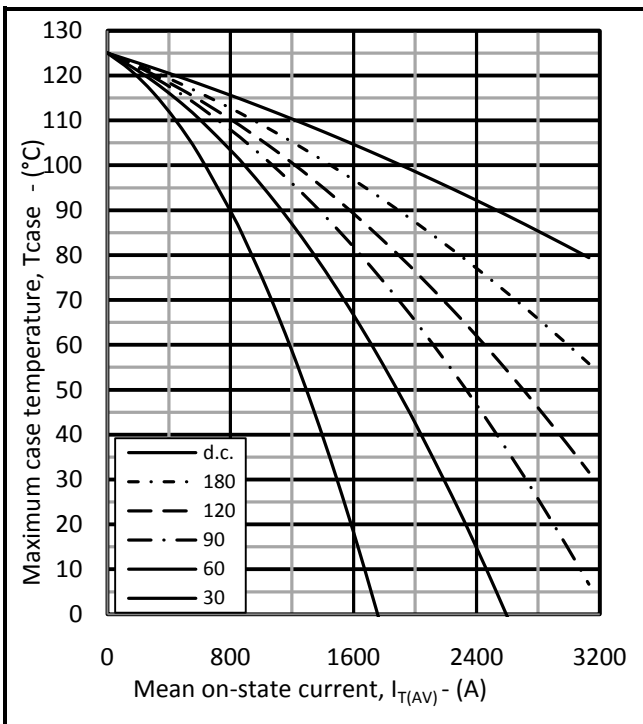


Fig.6 Maximum permissible case temperature, double side cooled – rectangular wave

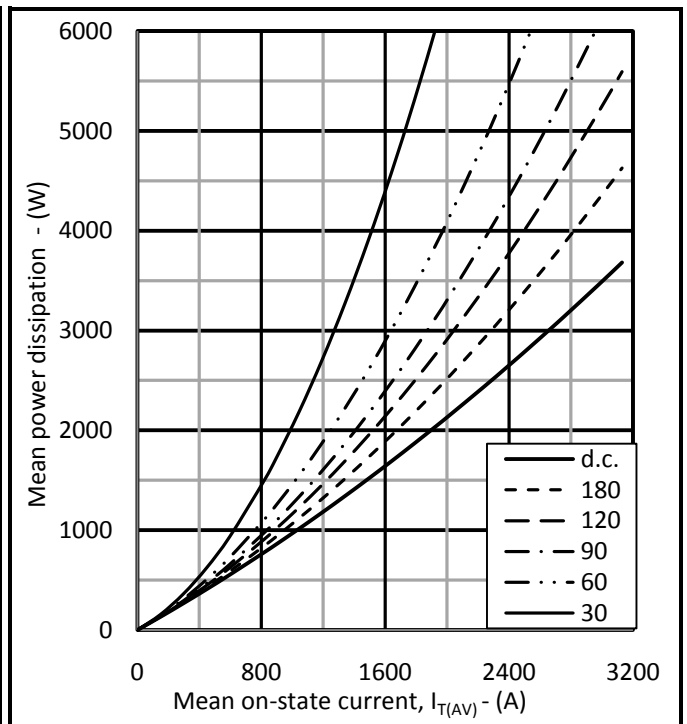


Fig.7 On-state power dissipation – rectangular wave

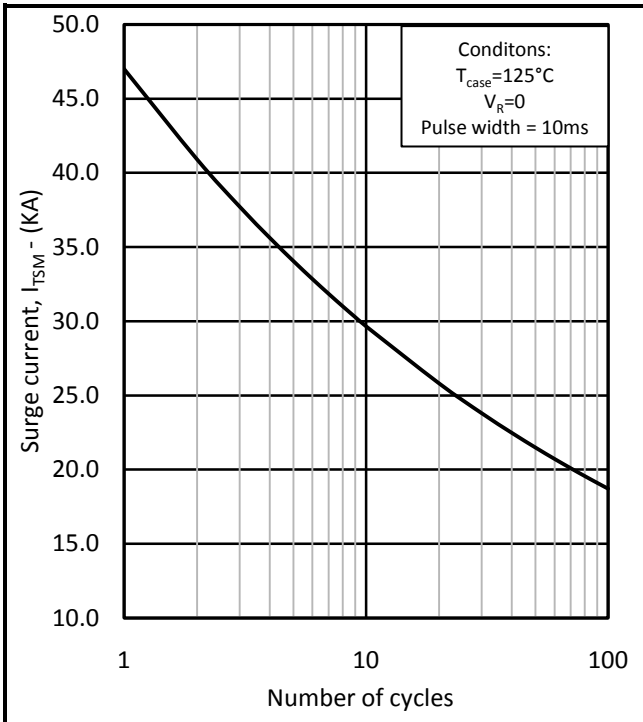


Fig.8 Multi-cycle surge current

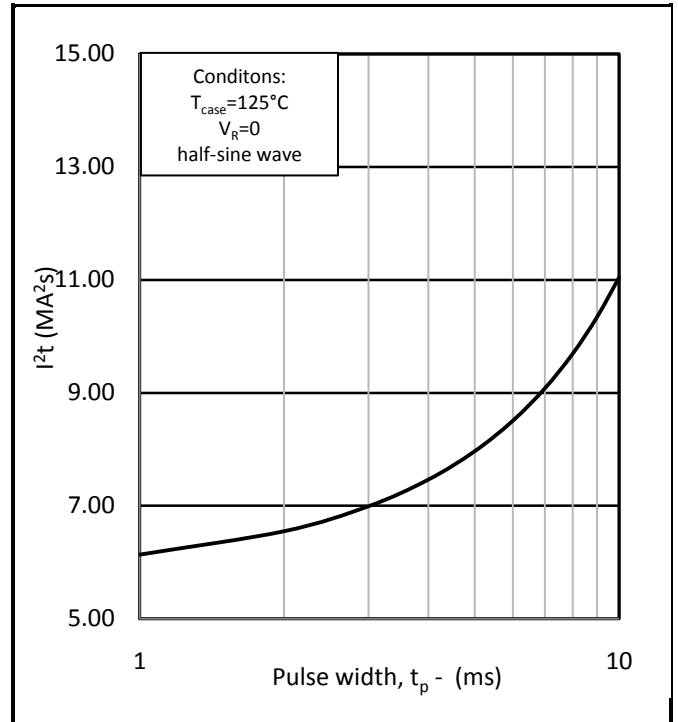


Fig.9 Single-cycle  $I^2t$

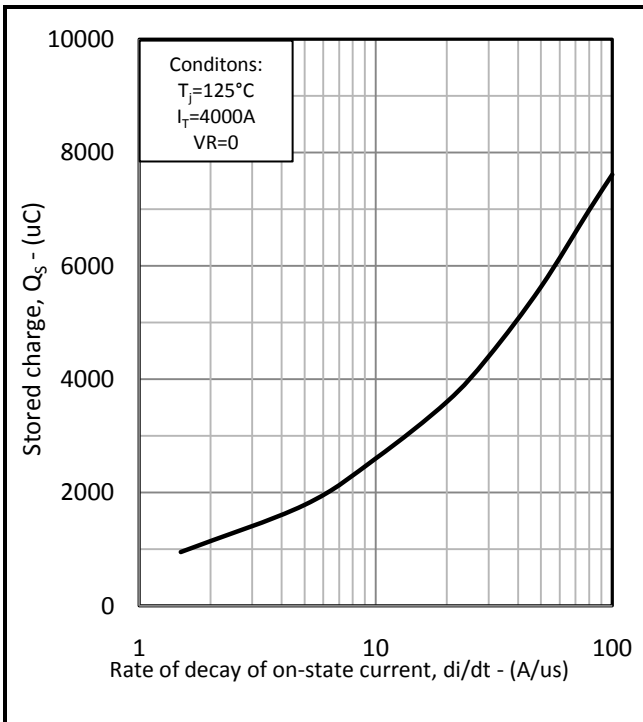


Fig.10 Stored charge vs  $di/dt$

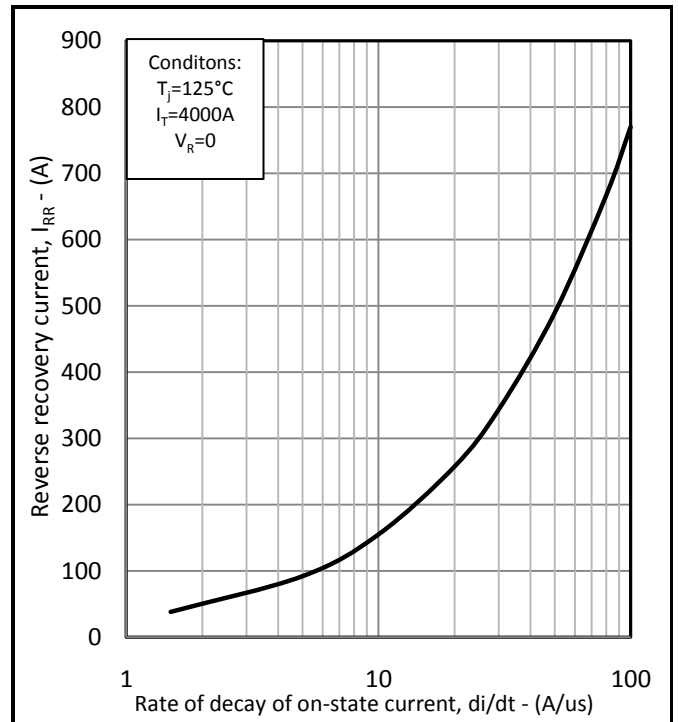


Fig.11 Reverse recovery current vs  $di/dt$

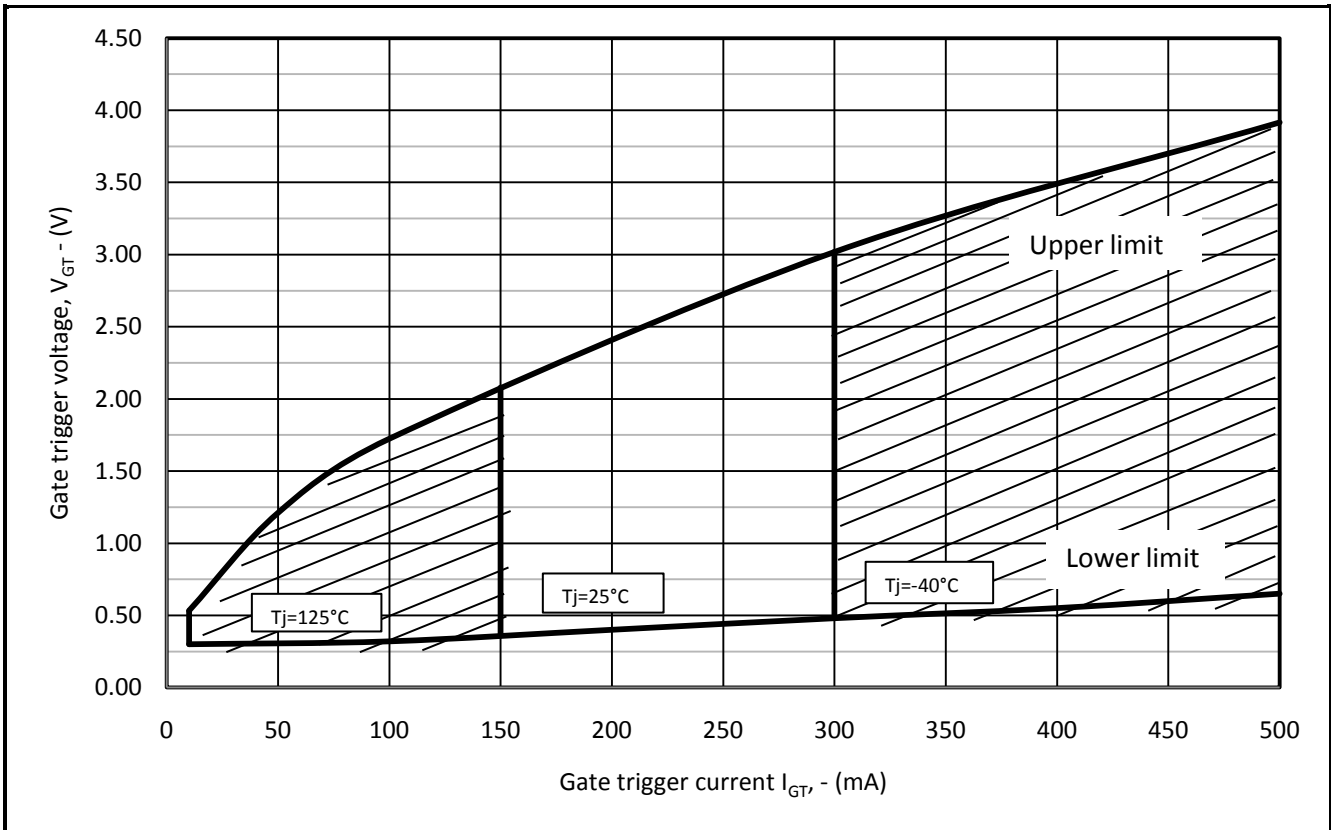
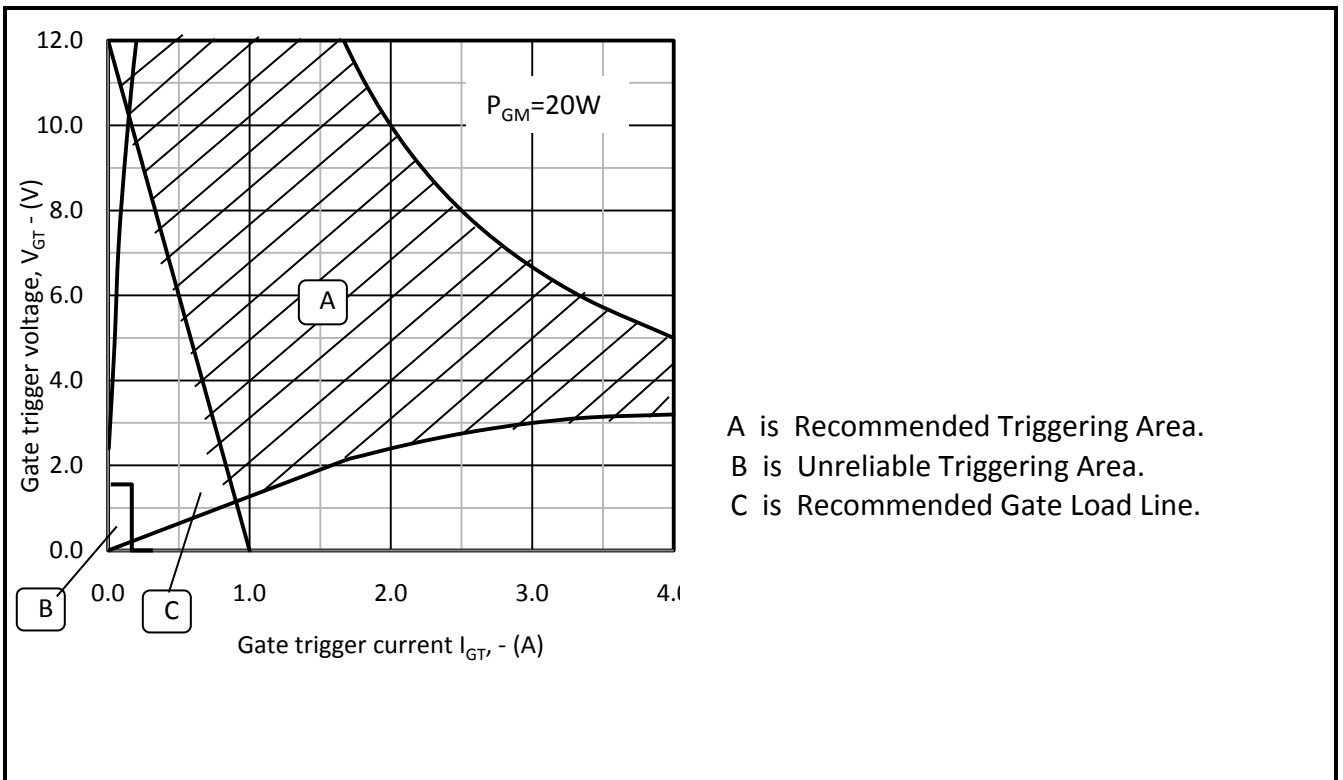


Fig.12 Gate characteristics

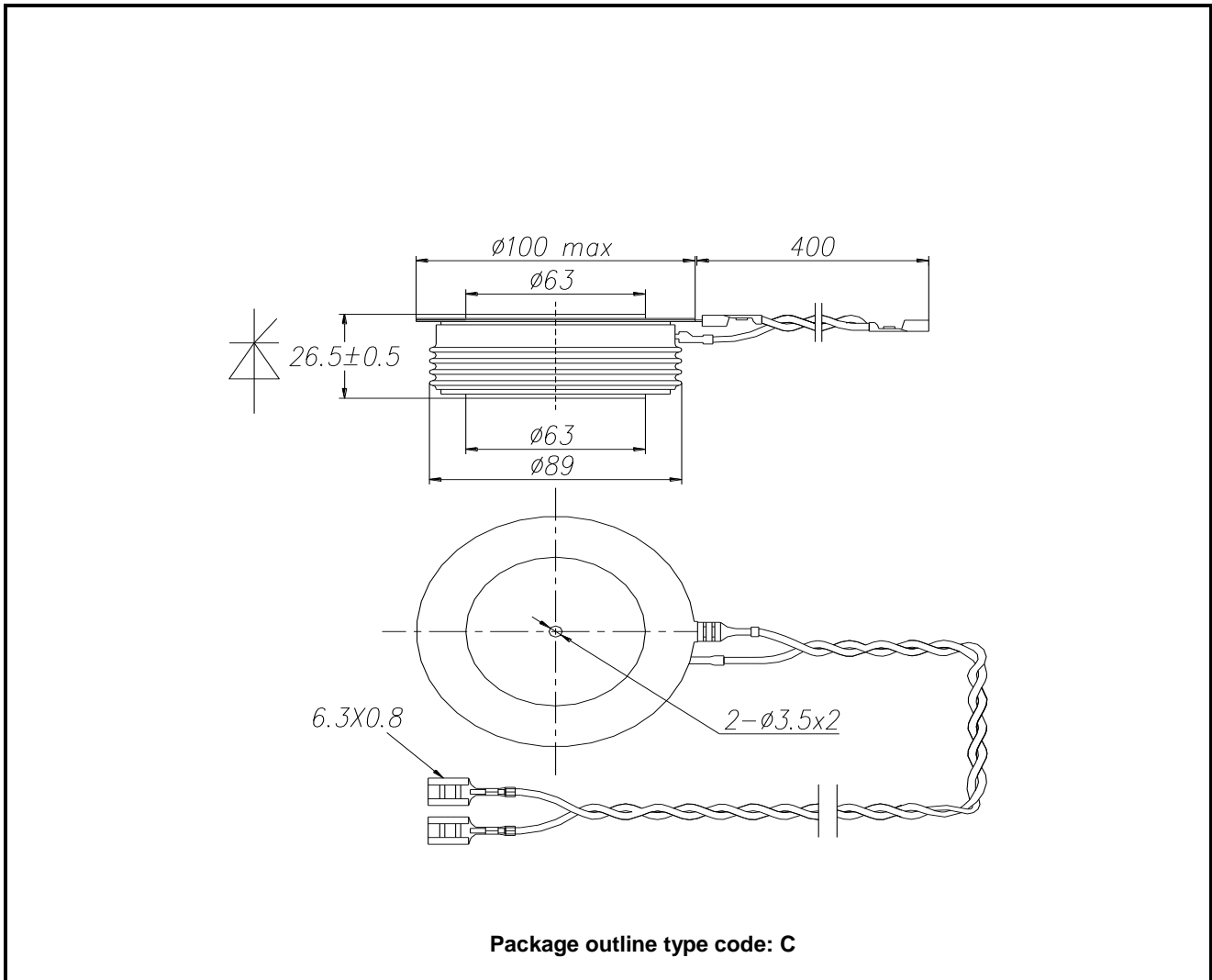


A is Recommended Triggering Area.  
B is Unreliable Triggering Area.  
C is Recommended Gate Load Line.

Fig.13 Gate characteristics

**PACKAGE DETAILS**

For further package information, please contact Customer Services. All dimensions in mm, unless stated otherwise. DO NOT SCALE.



**Fig.14 Package outline**



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